

Whole-device, resistive MHD simulations of Coaxial Helicity Injection in NSTX

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Goals for NSTX

Goals:

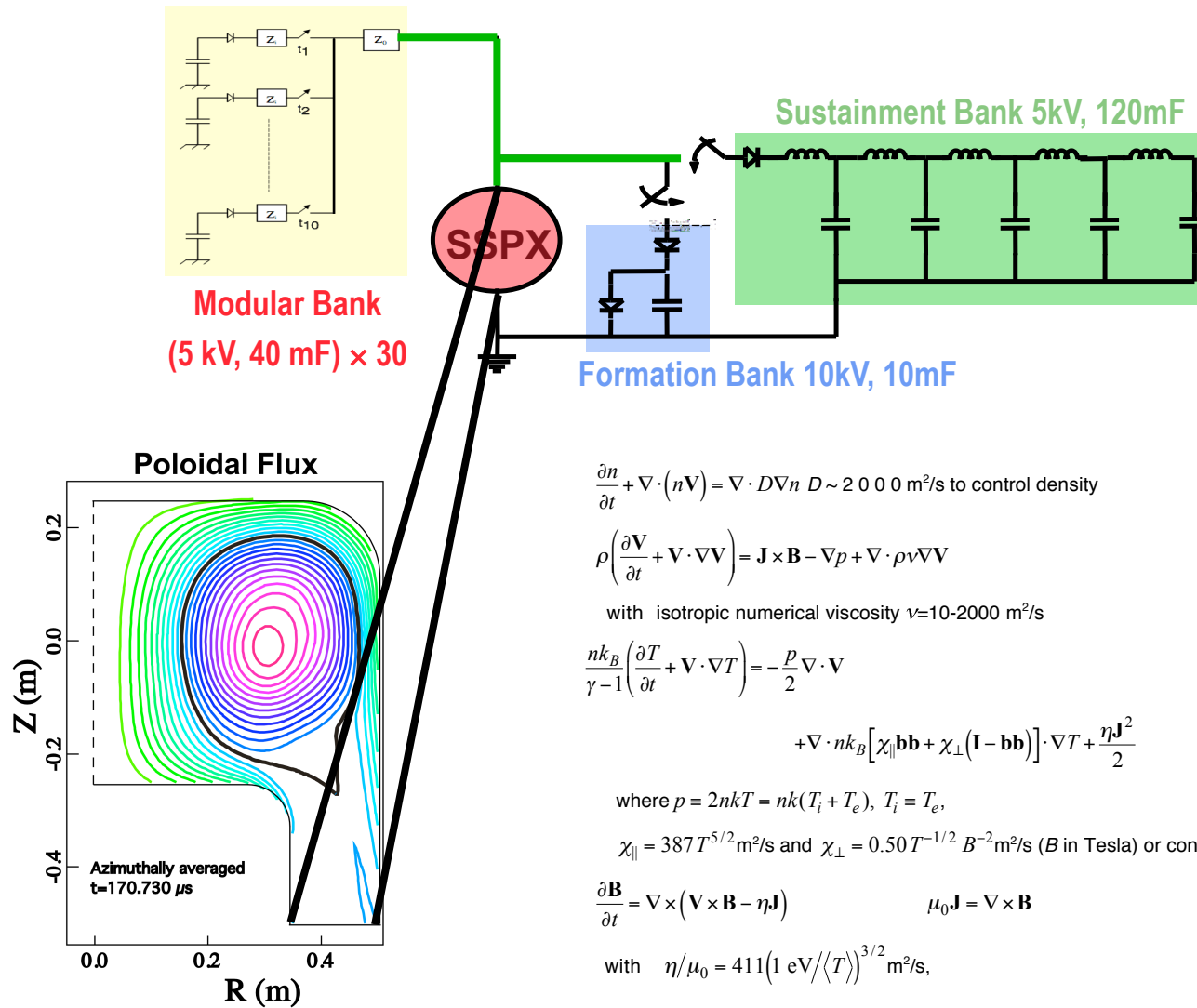
- **Support the experiment by strengthening understanding of the physics in an ST**
- **Couple the simulations closely with the experiment**
 - **Validate simulations and understand their strengths and weaknesses**
 - **Model specific experiments and a range of data**
- **Help optimize CHI for startup plasmas – apply ohmic induction to simulated results**

Modeling will be guided by the experimental results and needs

EXAMPLES FROM SSPX SIMULATIONS

COMPARISON WITH EXPERIMENT

Whole-device model of SSPX includes power systems and bias-coil magnets (not shown)



$$\frac{\partial n}{\partial t} + \nabla \cdot (n\mathbf{V}) = \nabla \cdot D\nabla n \quad D \sim 2.0 \times 10^{-2} \text{ m}^2/\text{s} \text{ to control density}$$

$$\rho \left(\frac{\partial \mathbf{V}}{\partial t} + \mathbf{V} \cdot \nabla \mathbf{V} \right) = \mathbf{J} \times \mathbf{B} - \nabla p + \nabla \cdot \rho \nu \nabla \mathbf{V}$$

with isotropic numerical viscosity $\nu = 10\text{-}2000 \text{ m}^2/\text{s}$

$$\frac{nk_B}{\gamma - 1} \left(\frac{\partial T}{\partial t} + \mathbf{V} \cdot \nabla T \right) = -\frac{p}{2} \nabla \cdot \mathbf{V}$$

$$+\nabla \cdot nk_B [\chi_{\parallel} \mathbf{b}\mathbf{b} + \chi_{\perp} (\mathbf{I} - \mathbf{b}\mathbf{b})] \cdot \nabla T + \frac{\eta \mathbf{J}^2}{2}$$

where $p = 2nkT = nk(T_i + T_e)$, $T_i = T_e$,

$\chi_{\parallel} = 387 T^{5/2} \text{ m}^2/\text{s}$ and $\chi_{\perp} = 0.50 T^{-1/2} B^{-2} \text{ m}^2/\text{s}$ (B in Tesla) or const.

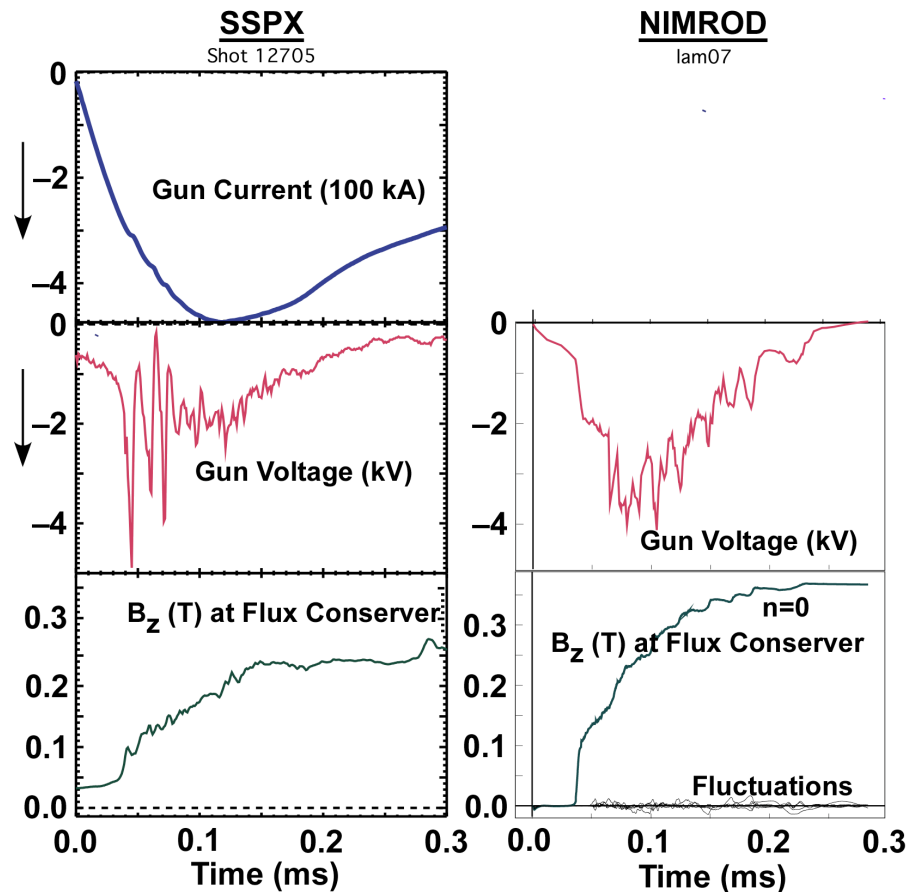
$$\frac{\partial \mathbf{B}}{\partial t} = \nabla \times (\mathbf{V} \times \mathbf{B} - \eta \mathbf{J}) \quad \mu_0 \mathbf{J} = \nabla \times \mathbf{B}$$

with $\eta/\mu_0 = 411 (1 \text{ eV}/\langle T \rangle)^{3/2} \text{ m}^2/\text{s}$,



Experiment and NIMROD —

Voltage spikes occur in both and have the same effect on building and sustaining the plasma



Compared are SSPX and NIMROD for identical gun currents

The “bubble-burst” of plasma from the gun is followed by voltage spikes

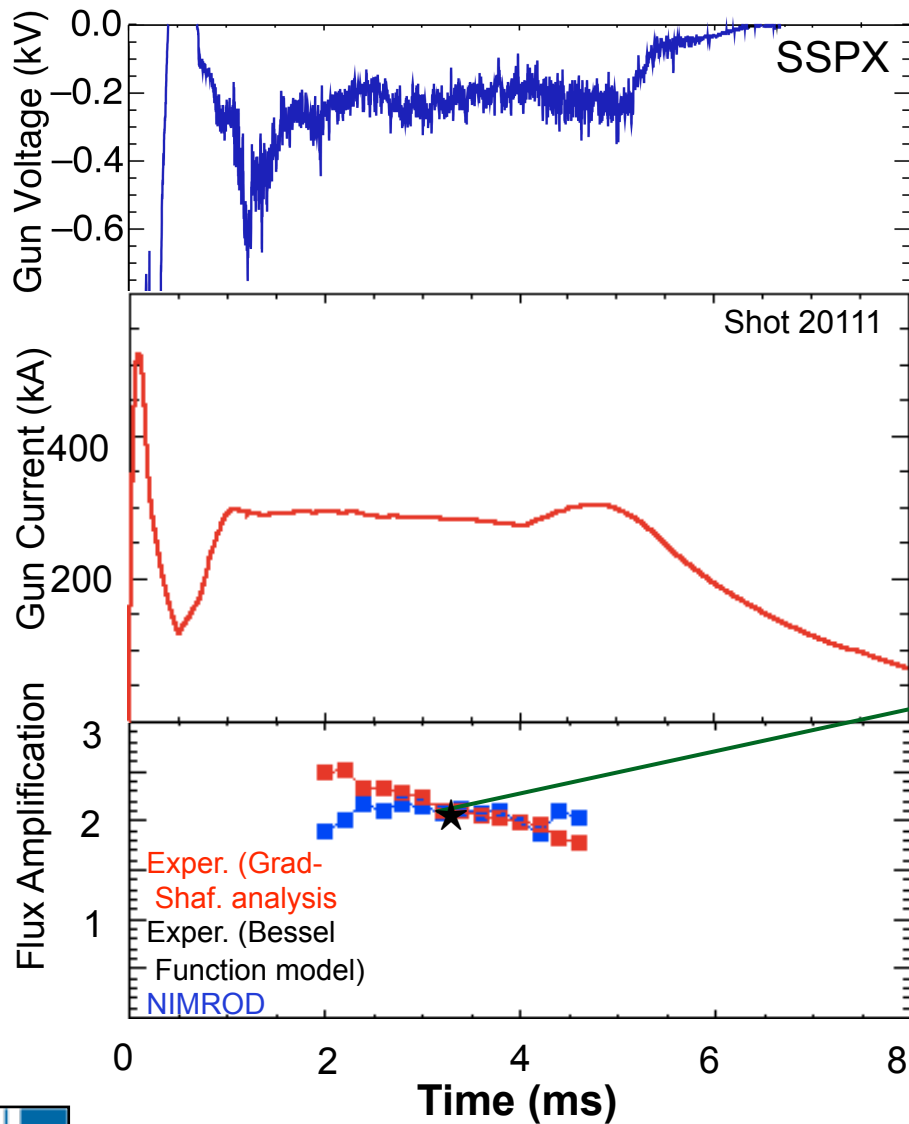
Toroidal flux is converted into poloidal flux at each spike

— **Reconnection**

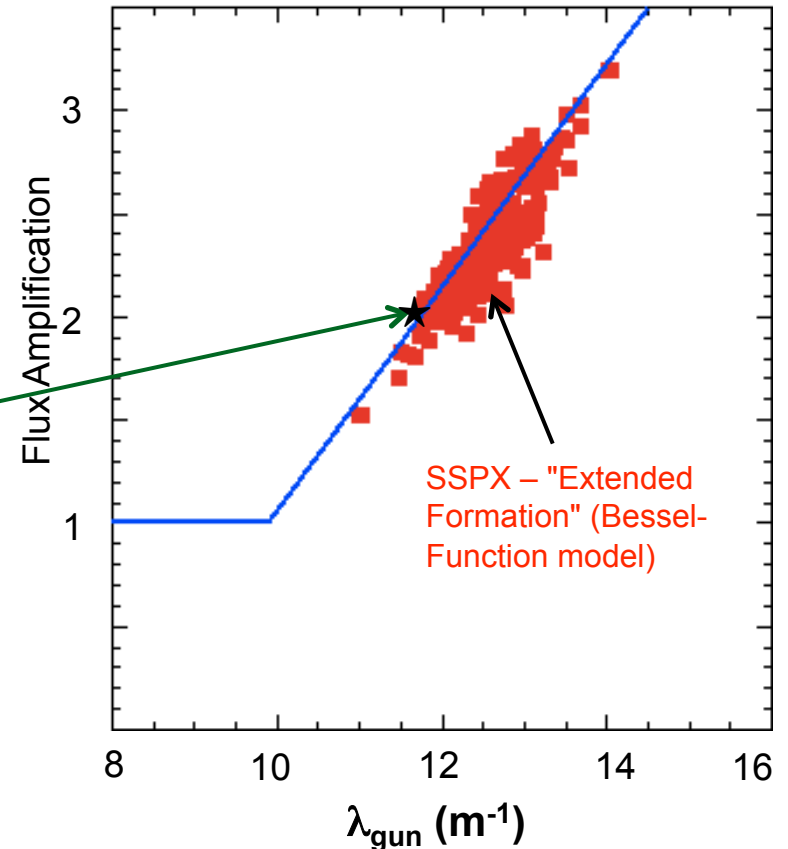
The magnetic oscillations (esp. $n=1$) – driven by the gun current – grow between voltage spikes and relax at the reconnection event



NIMROD Simulations Agree with Flux Amplification in SSPX

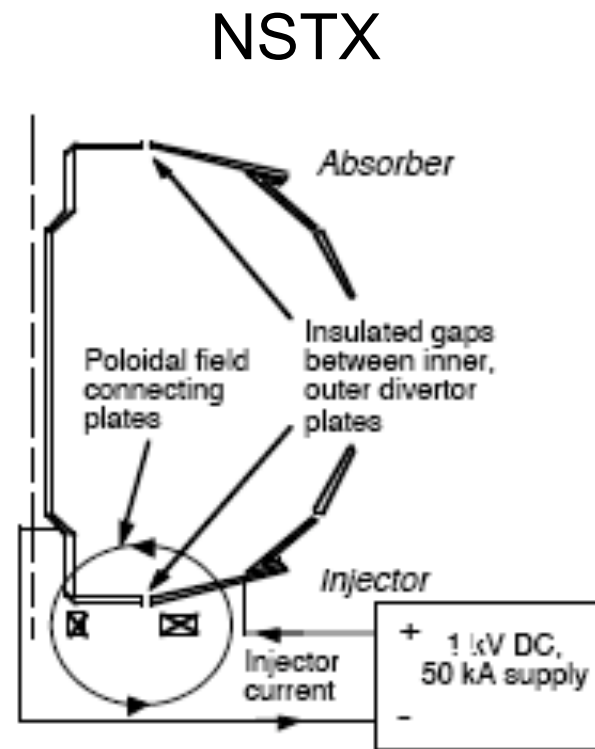
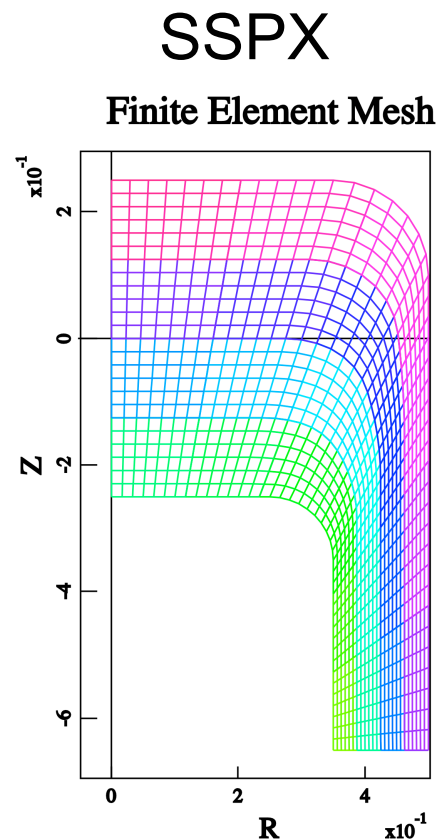


- NIMROD predicts the flux amplification in SSPX for current \approx constant
- Extended formation discharges scale with $\lambda_{\text{gun}} = \mu_0 I_{\text{gun}} / \psi_{\text{gun}}$ as predicted by NIMROD.



Note: For strong drive the agreement broke down. The reasons are not well understood

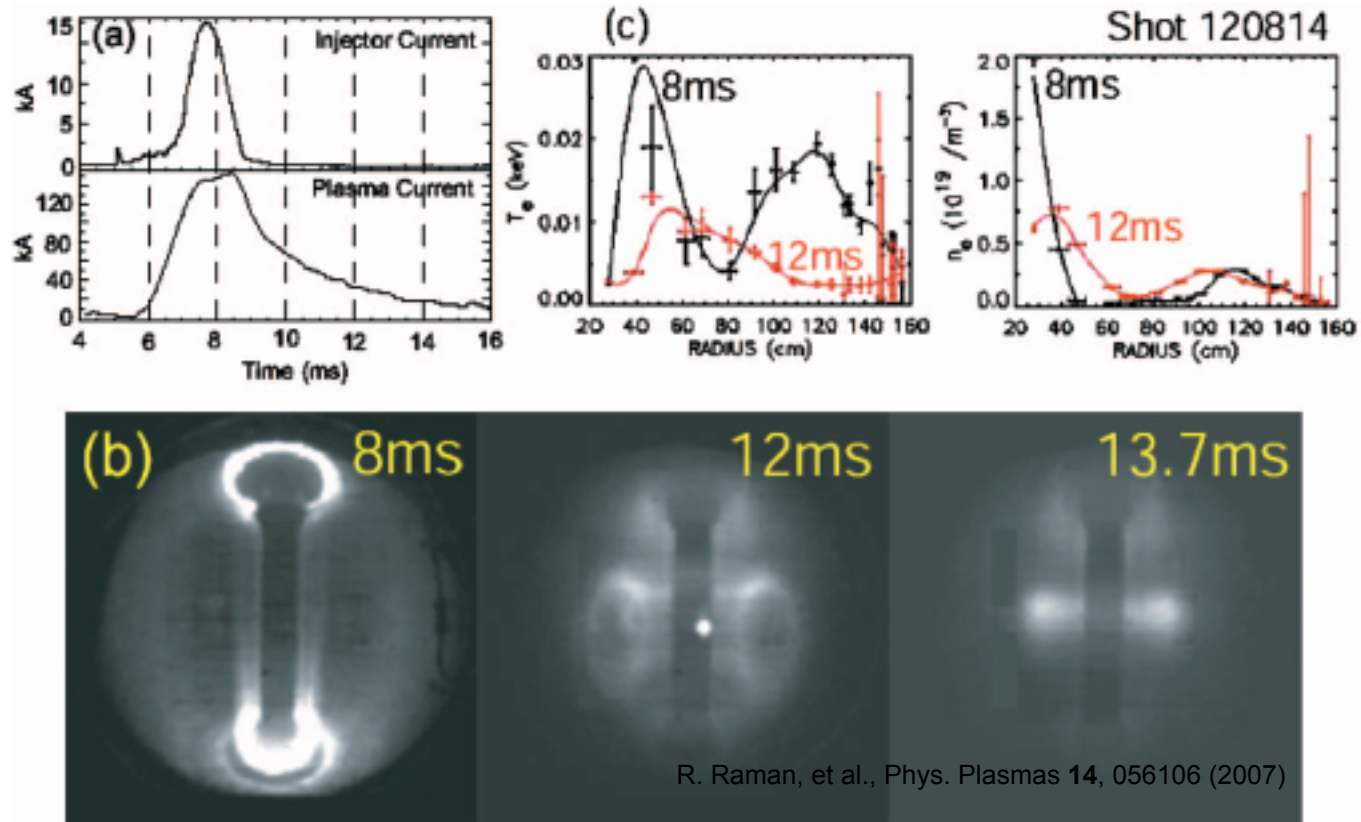
First step for NSTX — develop grid



The SSPX grid efficiently mapped the “gun” region into the spheromak volume

- The small size of the insulating gaps and localized ionization region in NSTX may make this more difficult
- It will probably be necessary to test and iterate the NSTX grid several times to optimize the grid for studying CHI

Second step — Model a simple startup shot



Summary

Simulation of a specific discharge will allow comparison of current and voltage, plasma behavior near the insulating gaps, plasma evolution, etc.

- Success will provide a basis for exploring detailed physics in the ST geometry. The physics of interest includes:
 - The CHI discharge formation
 - Current and flux amplification
 - The reconnection processes associated with expansion into the NSTX volume
 - Plasma behavior following reconnection
- Modeling will be closely coupled to the experiment and focus on the most immediate needs and interests